NSN 5961-00-855-2530

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-00-855-2530 **Inclosure Material:** Metal **Overall Length:** 0.340 inches **Overall Diameter:** 0.680 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 80.0 collector to base voltage, dc and 60.0 collector to emitter voltage, dc and 9.0 emitter to base voltage, dc **Current Rating Per Characteristic:** 5.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 50.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 wire hook Shelf Life: N/a **Unit Of Measure: Demilitarization:** No